

SCT4090KRHR

Automotive Grade N-channel SiC power MOSFET

V _{DSS}	1200V
R _{DS(on)} (Typ.)	90mΩ
I_{D}^{*1}	19A
P _D	88W

Outline



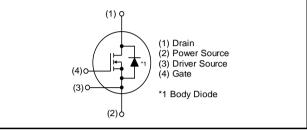
Features

- 1) Qualified to AEC-Q101
- 2) Low on-resistance
- 3) Fast switching speed
- 4) Fast reverse recovery
- 5) Easy to parallel
- 6) Simple to drive
- 7) Pb-free lead plating ; RoHS compliant

Application

- Automobile
- · Switch mode power supplies

Inner circuit



Please note Driver Source and Power Source are not exchangeable. Their exchange might lead to malfunction.

Packaging specifications

	Packing	Tube
	Reel size (mm)	-
Tuno	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	30
	Taping code	C15
	Marking	SCT4090KR

•Absolute maximum ratings ($T_{vj} = 25^{\circ}C$ unless otherwise specified)

Parameter		Symbol	Value	Unit	
Drain - source voltage		V _{DSS}	1200	V	
Continuous drain	V - V	$T_c = 25^{\circ}C$	ا _D , I _S ^{*1}	19	А
and source current	$V_{GS} = V_{GS_{on}}$	$T_c = 100^{\circ}C$		13	А
Pulsed drain current	$V_{GS} = V_{GS_{on}}$	$T_c = 25^{\circ}C$	I _{D,pulse} *2	45	А
Body diode pulsed forward current $T_c = 25^{\circ}C$		I _{S,pulse} *1,*3	19	А	
Body diode surge forward current		$V_{GS} = 0 V$	1,*4 ^{*1,*4}	45	А
Gate - source voltage (DC)		$V_{GSS_{DC}}$	-4 to +21	V	
Gate - source surge vol	tage (t _{surge} < 300)ns)	V_{GSS_surge} *5	-4 to +23	V
Recommended turn-on gate - source drive voltage		$V_{GS_{on}}$ *6	+15 to +18	V	
Recommended turn-off gate - source drive voltage		V _{GS_off}	0	V	
Virtual junction temperature		T _{vj}	175	°C	
Range of storage temperature		T _{stg}	-40 to +175	°C	

•Electrical characteristics ($T_{vj} = 25^{\circ}C$ unless otherwise specified)

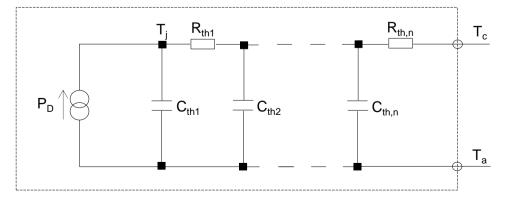
Deremeter	Cumphal	Conditions		Unit			
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Drain - Source breakdown	V	$V_{GS} = 0 V, I_{D} = 3.7 mA$				V	
voltage	V _{(BR)DSS}	T _{vj} = 25°C	1200	-	-	V	
		$V_{GS} = 0 V, V_{DS} = 1200V$					
Zero Gate voltage Drain current	I _{DSS}	T _{vj} = 25°C	-	1	80	μA	
		T _{vj} = 150°C	-	10	-		
Gate - Source leakage current	I _{GSS+}	V_{GS} = +21V , V_{DS} = 0V	-	-	100	nA	
Gate - Source leakage current		$V_{GS} = -4V$, $V_{DS} = 0V$	-	-	-100	nA	
Gate threshold voltage	$V_{GS(th)}{}^{*7}$	$V_{DS} = 10V, I_{D} = 4.44mA$	2.8	-	4.8	V	
		$V_{GS} = 18V, I_{D} = 8.3A$					
Static Drain - Source on - state resistance	${\sf R}_{\sf DS(on)}$ *8	T _{vj} = 25°C	-	90	117	mΩ	
		T _{vj} = 150°C	-	180	-		
Gate input resistance	R_G	f = 1MHz, open drain	-	4	-	Ω	

Thermal resistance

Parameter	Symbol	Values			Unit
Farameter	Symbol	Min.	Тур.	Max.	Offic
Thermal resistance, junction - case	${\sf R_{thJC}}^{*9}$	-	1.3	1.7	K/W

•Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R _{th1}	1.8 ×10 ⁻¹		C _{th1}	4.2 ×10 ⁻⁴	
R _{th2}	6.7 ×10 ⁻¹	K/W	C _{th2}	1.9 ×10 ⁻³	Ws/K
R _{th3}	4.8 ×10 ⁻¹		C _{th3}	4.8 ×10 ⁻²	





•Electrical characteristics (T_{vj} = 25°C unless otherwise specified)

Demonster	O week al	nhal Conditions		Values			
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Transconductance	g _{fs} *8	$V_{DS} = 10V, I_{D} = 8.3A$	-	4.1	-	S	
Input capacitance	C _{iss}	$V_{GS} = 0V$	-	1026	-	pF	
Output capacitance	C _{oss}	V _{DS} = 800V	-	35	-		
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	3	-		
Effective output capacitance, energy related	C _{o(er)}	$V_{GS} = 0V$ $V_{DS} = 0V$ to 800V	-	44	-	pF	
Total Gate charge	Q _g *8	$V_{DS} = 800V$ $I_{D} = 8.3A$	-	48	-		
Gate - Source charge	Q _{gs} *8	V _{GS} = 18V	-	11	-	nC	
Gate - Drain charge	Q _{gd} *8	Q _{gd} *8 See Fig. 1-1, 1-2.		16	-		
Turn - on delay time	t _{d(on)} *8	$V_{DS} = 800V$ $I_{D} = 8.3A$	-	4.4	-		
Rise time	t _r *8	V _{GS} = +18V / 0V	-	9.8	-	ns	
Turn - off delay time	t _{d(off)} *8	$R_G = 0\Omega, L = 250\mu H$ E _{on} includes diode	-	19	-	115	
Fall time	t _f *8	reverse recovery $L_{\sigma} = 50$ nH, $C_{\sigma} = 10$ pF	-	16	-		
Turn - on switching loss	E _{on} *8	See Fig. 2-1, 2-2, 2-3.	-	100	-		
Turn - off switching loss	E _{off} *8		-	9	-	μJ	
V _{GS(on)} = +15V Short-circuit	t _{sc} *10	V _{DS} ≤ 800V V _{DS,peak} ≤ 1200V	-	4.5	-	μs	
withstand time $V_{GS(on)} = +18V$	L _{SC}	$T_{vj(start)} = 25^{\circ}C$ $R_{G} = 2.2\Omega$	-	4.0	-	μs	



•Body diode electrical characteristics (Source-Drain) (T_{vi} = 25°C unless otherwise specified)

Doromotor	Symbol Conditions		Values			Unit	
Parameter			Min.	Тур.	Max.	Unit	
Forward voltage	V_{SD}^{*8}	$V_{GS} = 0V, I_S = 8.3A$	-	3.3	-	V	
Reverse recovery time	t _{rr} *8	$I_F = 8.3A$ $V_R = 800V$	-	8.5	-	ns	
Reverse recovery charge	Q _{rr} *8	di/dt = 3000A/µs	-	90	-	nC	
Peak reverse recovery current	I _{rrm} *8	$L_{\sigma} = 50$ nH, $C_{\sigma} = 10$ pF See Fig. 3-1, 3-2.	-	21	-	А	

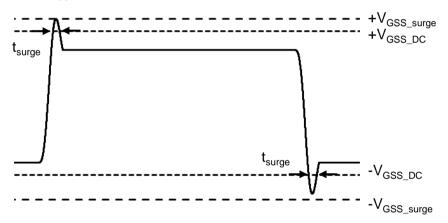
*1 Limited by maximum T_{vi} and for Max. R_{thJC} .

*2 Pulse width and duty cycle are limited by $T_{vj,max}$.

*3 Only for body-diode, Repetitive pulse, PW \leq 1.5µs, Duty cycle \leq 5%

*4 When used as a protective function, PW \leq 10µs

*5 Example of acceptable V_{GS} waveform



Please note especially when using driver source that $V_{\mbox{GSS_surge}}$ must be in the range of absolute maximum rating.

- *6 Please be advised not to use SiC-MOSFETs with V_{GS} below 10V as doing so may cause thermal runaway.
- *7 Tested after applying $V_{GS} = 21V$ for 100ms.

*8 Pulsed

*9 Measured conformable to JESD51-14.

See the application note "rthjc_measurement_and_usage_an-e.pdf". Link

 ${\tt URL: https://fscdn.rohm.com/en/products/databook/applinote/discrete/common/rthjc_measurement_and_usage_an-e.pdf}$

*10 Single pulsed.



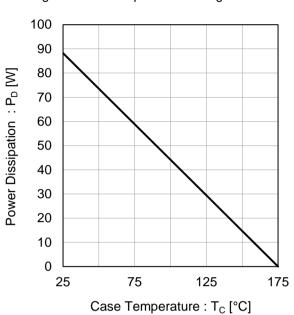


Fig.1 Power Dissipation Derating Curve Fig.2 Maximum Safe Operating Area

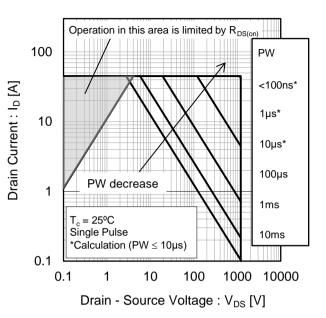
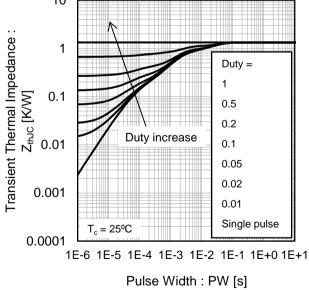
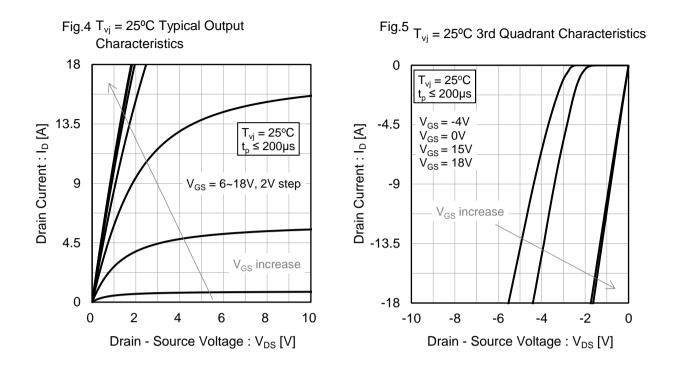


Fig.3 Typical Transient Thermal Impedance vs. Pulse Width

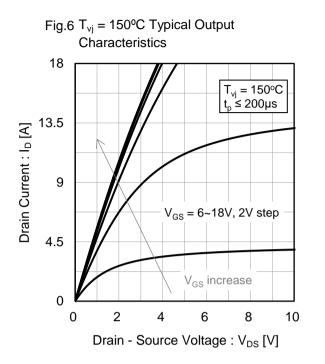


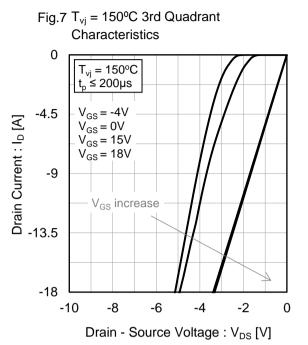
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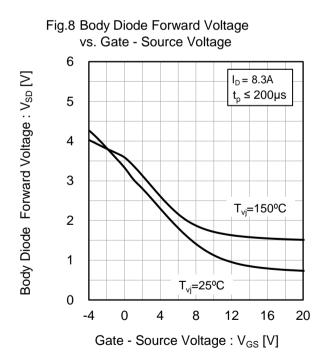














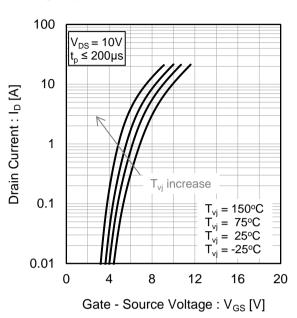
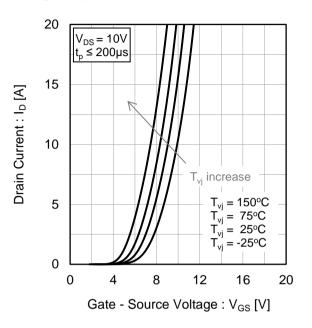


Fig.9 Typical Transfer Characteristics (I)

Fig.10 Typical Transfer Characteristics (II)



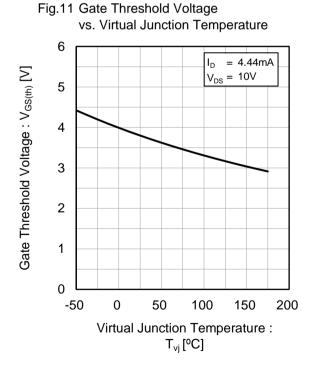
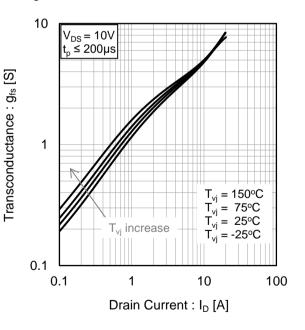
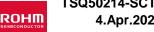
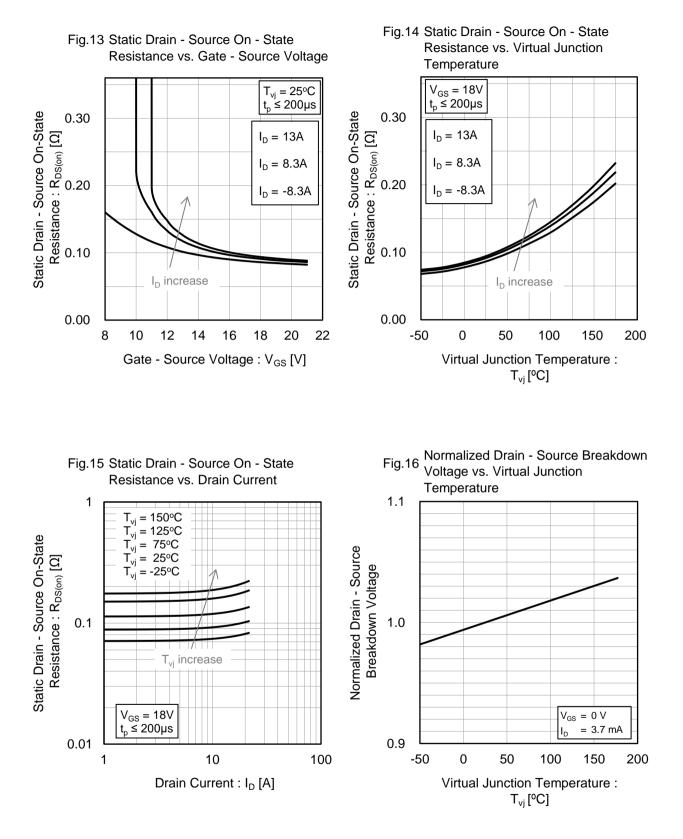


Fig.12 Transconductance vs. Drain Current



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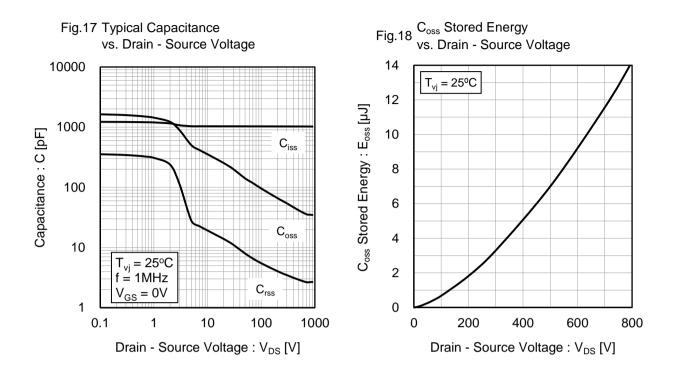
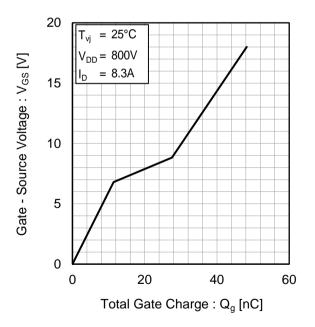
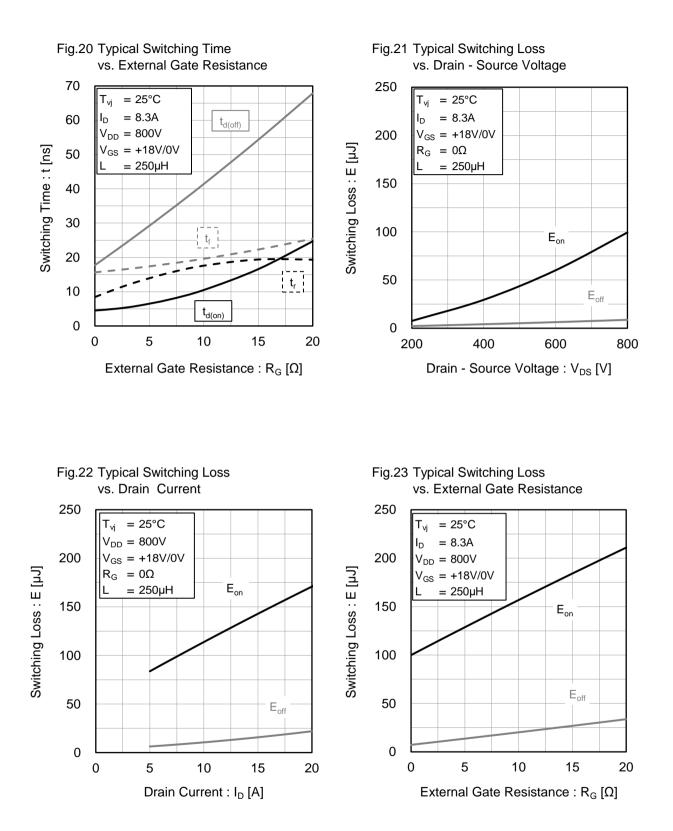


Fig.19 Dynamic Input Characteristics

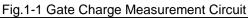








Measurement circuits and waveforms



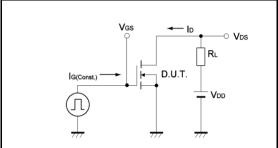


Fig.2-1 Switching Characteristics Measurement Circuit

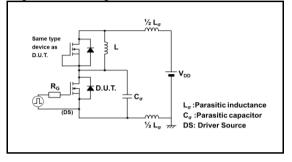


Fig.2-3 Waveforms for Switching Energy Loss

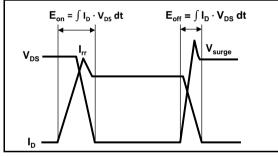


Fig.3-1 Reverse Recovery Time Measurement Circuit

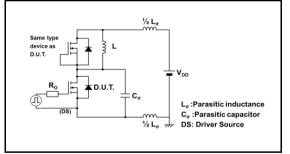


Fig.1-2 Gate Charge Waveform

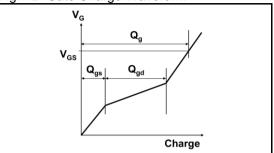


Fig.2-2 Waveforms for Switching Time

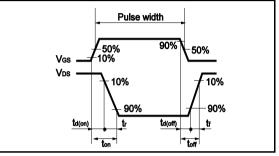
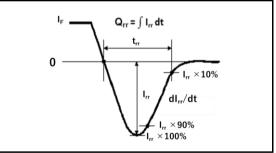
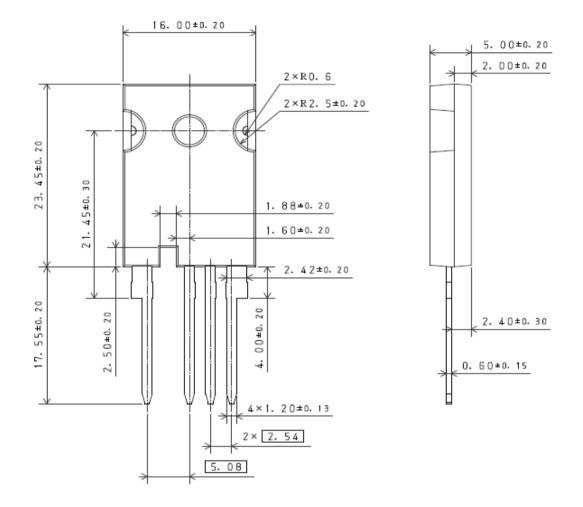


Fig.3-2 Reverse Recovery Waveform





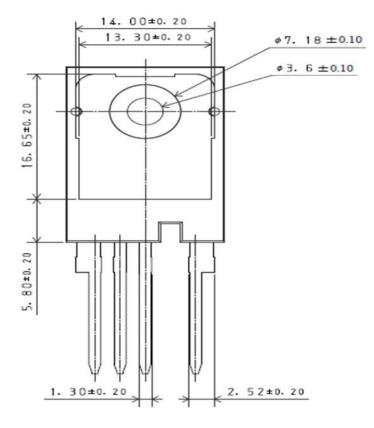
Package Dimensions



Unit: mm







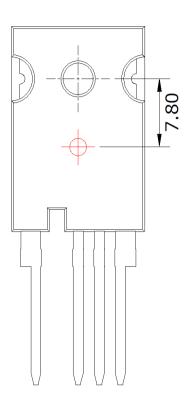
Unit: mm





Die Bonding Layout





•Front view of the packaging.

•Dimensions are design values.

·If the heat sink is to be installed, it should be in contact with the die bonding point.

Unit: mm





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